

VHF/UHF WIDE BAND AMPLIFIER APPLICATION.

FEATURES

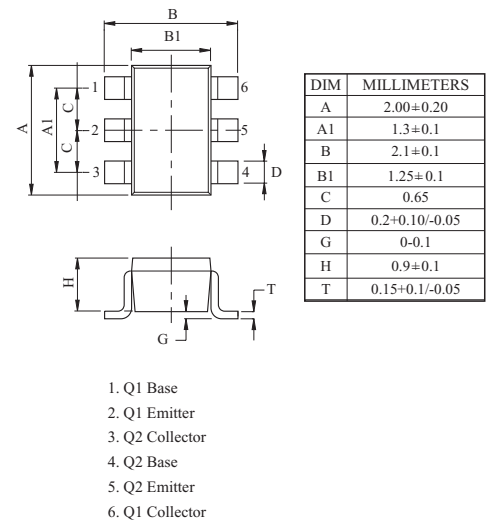
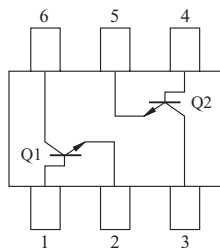
- Low Noise Figure, High Gain.
- $NF=1.1dB$, $|S_{21e}|^2=13dB$ ($f=1GHz$).
- Two internal isolated Transistors in one package.

MAXIMUM RATING (Ta=25 °C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	20	V
Collector-Emitter Voltage	V_{CEO}	10	V
Emitter-Base Voltage	V_{EBO}	1.5	V
Collector Current	I_C	40	mA
Collector Power Dissipation	P_C^*	200	mW
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	-55 ~ 150	°C

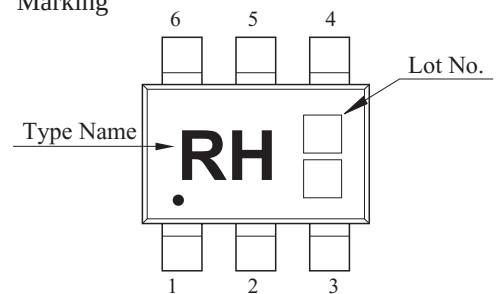
*Total Rating

EQUIVALENT CIRCUIT (Top View)



US6

Marking

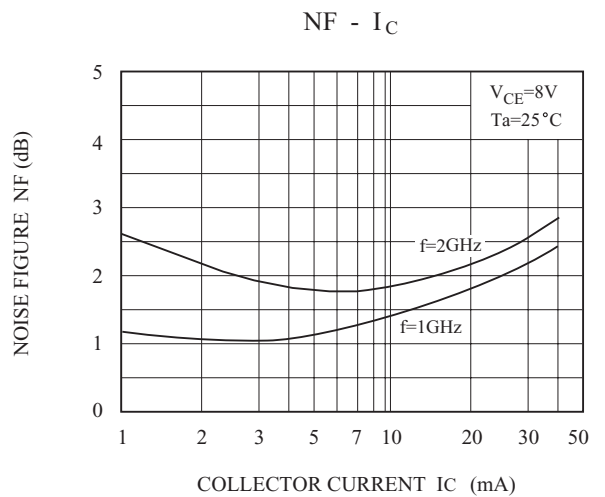
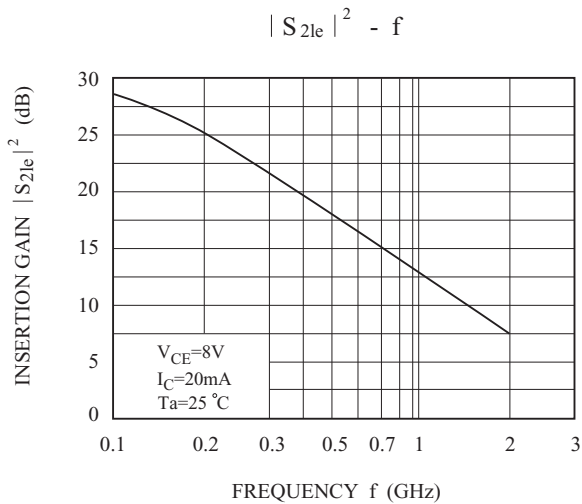
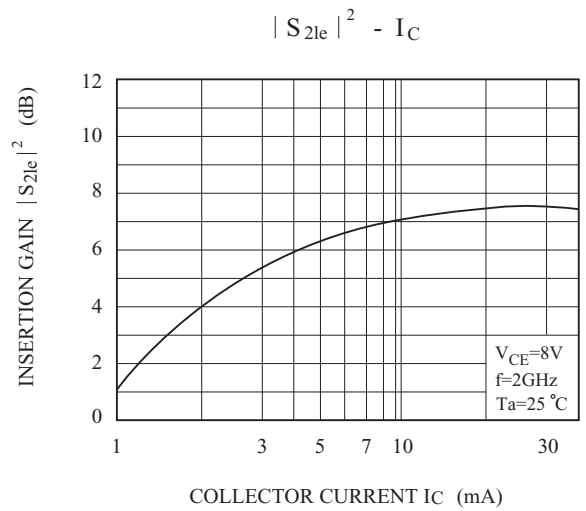
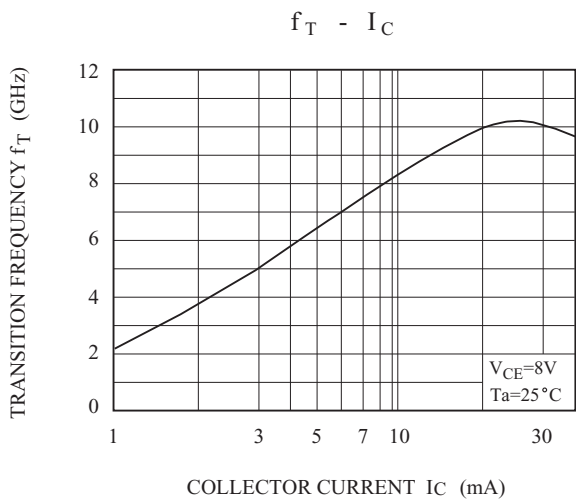
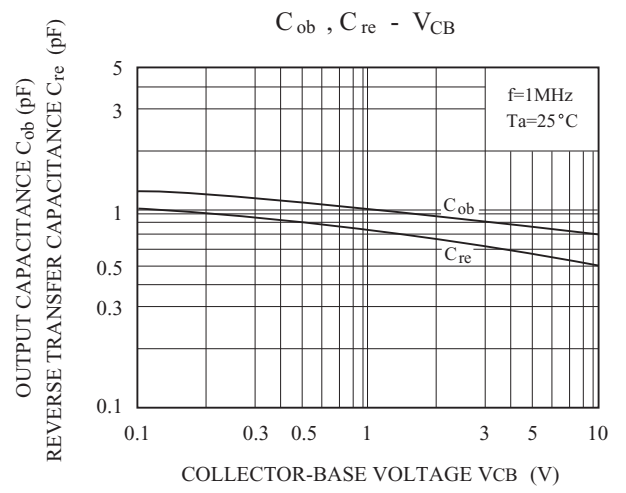
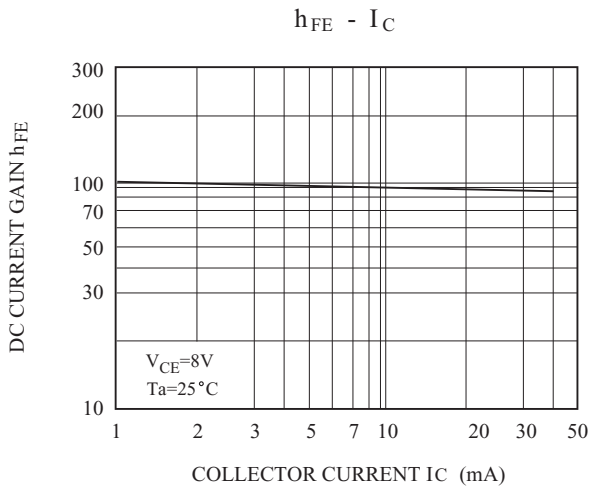


CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB}=10V$, $I_E=0$	-	-	1	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB}=1V$, $I_C=0$	-	-	1	μA
DC Current Gain	h_{FE} (Note1)	$V_{CE}=8V$, $I_C=20mA$	50	-	250	-
Collector Output Capacitance	C_{ob}	$V_{CB}=10V$, $I_E=0$, $f=1MHz$ (Note2)	-	0.7	-	pF
Reverse Transfer Capacitance	C_{re}		-	0.5	0.95	pF
Transition Frequency	f_T	$V_{CE}=8V$, $I_C=20mA$	7	10	-	GHz
Insertion Gain	$ S_{21e} ^2$ (1)	$V_{CE}=8V$, $I_C=20mA$, $f=1GHz$	10	13	-	dB
	$ S_{21e} ^2$ (2)	$V_{CE}=8V$, $I_C=20mA$, $f=2GHz$	-	7	-	dB
Noise Figure	NF (1)	$V_{CE}=8V$, $I_C=5mA$, $f=1GHz$	-	1.1	2.5	dB
	NF (2)	$V_{CE}=8V$, $I_C=5mA$, $f=2GHz$	-	1.7	-	dB

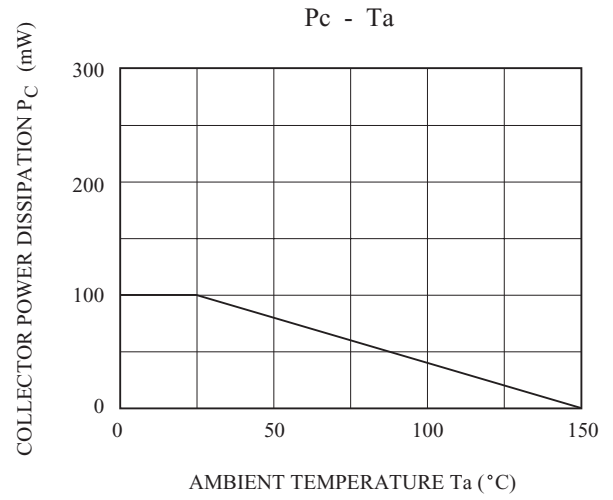
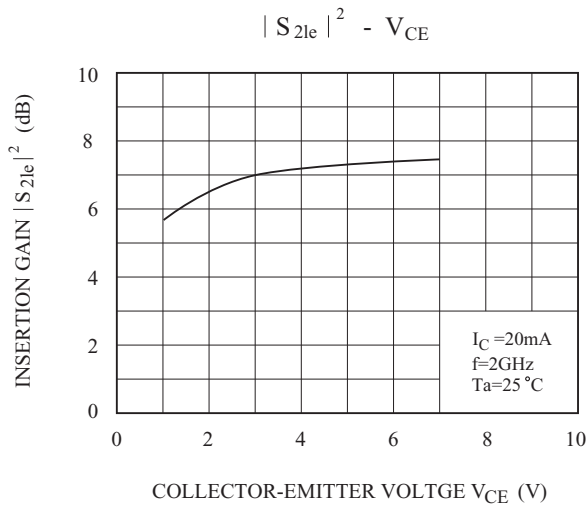
Note 1 : h_{FE} Classification H:50~100, J:80~160, K:125~250

Note 2 : C_{re} is measured by 3 terminal method with capacitance bridge.

TYPICAL CHARACTERISTICS (Ta=25°C)



KTC3605U



S-PARAMETER

($V_{CE}=8V$, $I_C=5mA$, $Z_O=50\ \Omega$, $T_a=25^\circ C$)

Frequency (MHz)	$ S_{11} $		$ S_{21} $		$ S_{12} $		$ S_{22} $	
	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.
200	0.683	-50.1	10.186	138.3	0.049	62.0	0.773	-30.0
400	0.462	-86.9	7.472	114.6	0.071	54.3	0.556	-39.6
600	0.343	-113.1	5.618	100.9	0.086	53.8	0.448	-41.7
800	0.282	-133.6	4.407	91.7	0.101	55.3	0.392	-41.6
1000	0.249	-151.0	3.663	84.7	0.115	57.2	0.360	-41.7
1200	0.236	-166.6	3.128	78.7	0.131	58.9	0.339	-41.7
1400	0.233	179.7	2.759	73.1	0.150	60.1	0.330	-42.8
1600	0.234	168.3	2.457	68.2	0.168	60.0	0.319	-45.0
1800	0.238	158.6	2.224	63.4	0.185	60.0	0.311	-47.9
2000	0.251	149.6	2.038	59.4	0.203	60.4	0.302	-50.2

($V_{CE}=8V$, $I_C=20mA$, $Z_O=50\ \Omega$, $T_a=25^\circ C$)

Frequency (MHz)	$ S_{11} $		$ S_{21} $		$ S_{12} $		$ S_{22} $	
	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.
200	0.319	-91.9	18.338	116.7	0.033	65.3	0.494	-43.5
400	0.213	-134.2	10.303	99.2	0.054	68.9	0.312	-42.4
600	0.185	-160.0	7.111	90.3	0.076	70.8	0.258	-37.6
800	0.176	-178.2	5.415	84.3	0.098	71.2	0.236	-34.3
1000	0.174	167.8	4.400	79.2	0.120	71.1	0.228	-32.0
1200	0.178	156.8	3.712	74.8	0.143	70.3	0.226	-31.5
1400	0.186	147.5	3.236	70.3	0.168	68.7	0.226	-32.8
1600	0.194	139.7	2.874	66.3	0.190	66.6	0.223	-35.9
1800	0.199	133.7	2.583	62.6	0.211	64.9	0.216	-39.0
2000	0.215	127.8	2.369	58.8	0.232	63.5	0.211	-41.9

KTC3605U

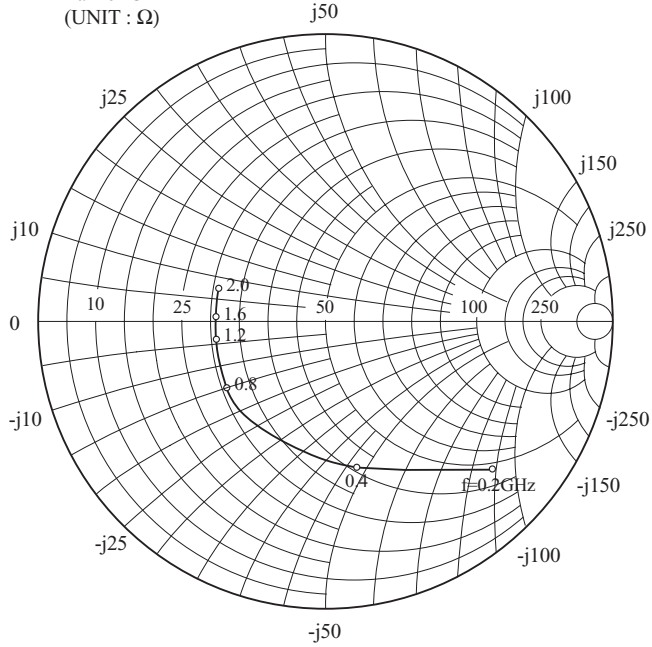
S_{11e}

$V_{CE}=8V$

$I_C=5mA$

$T_a=25^{\circ}C$

(UNIT : Ω)

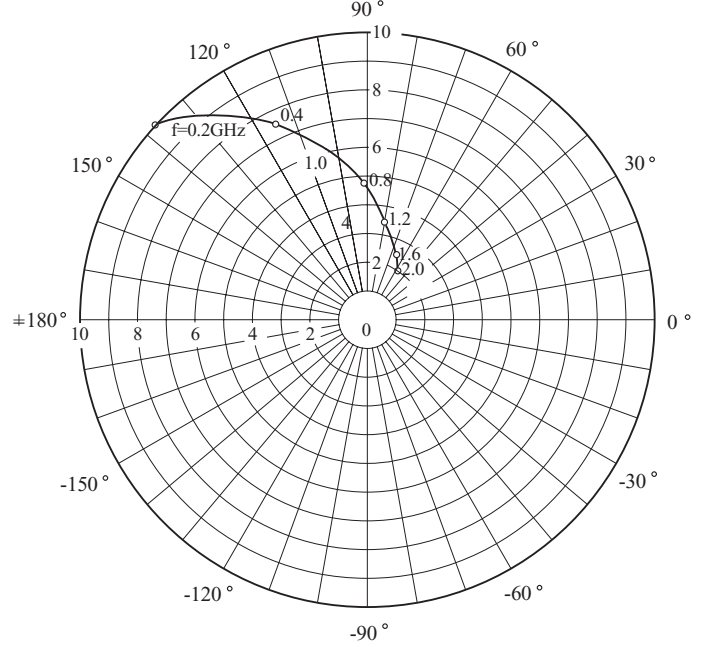


S_{21e}

$V_{CE}=8V$

$I_C=5mA$

$T_a=25^{\circ}C$

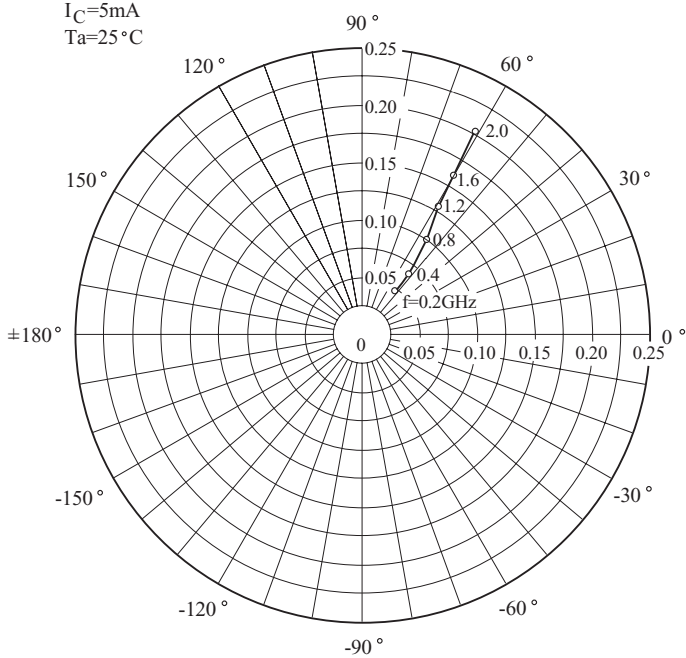


S_{12e}

$V_{CE}=8V$

$I_C=5mA$

$T_a=25^{\circ}C$



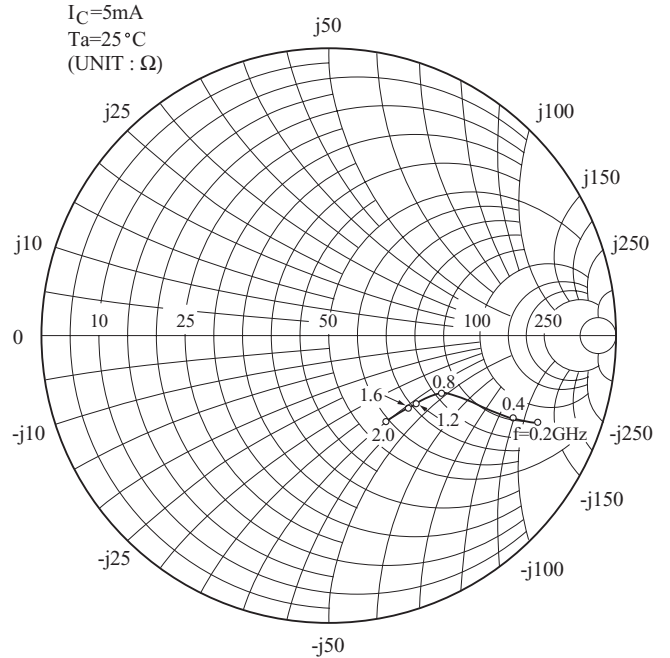
S_{22e}

$V_{CE}=8V$

$I_C=5mA$

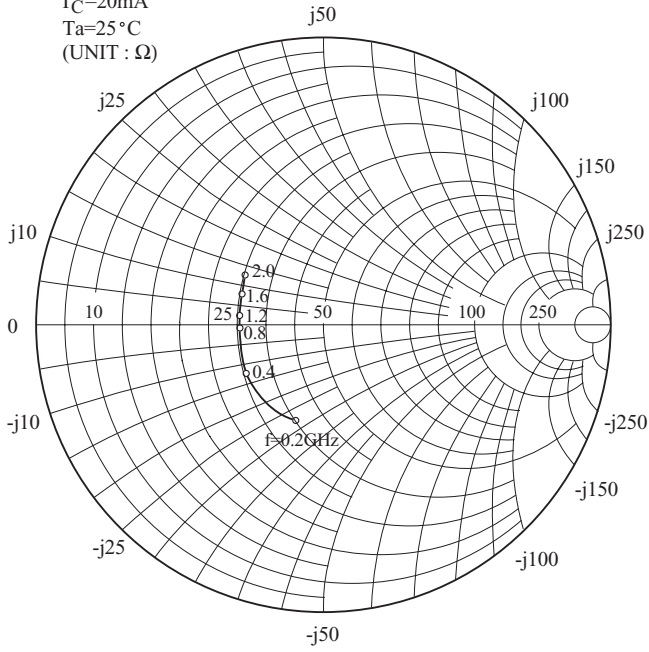
$T_a=25^{\circ}C$

(UNIT : Ω)

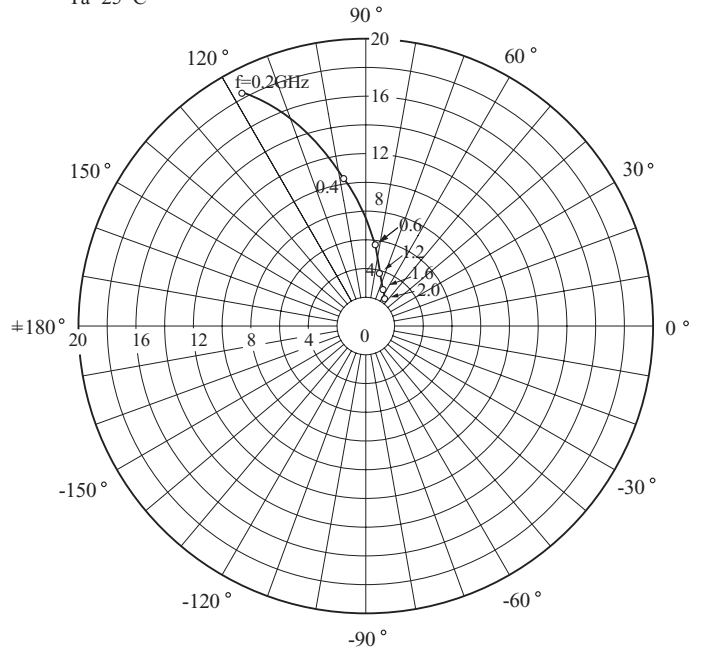


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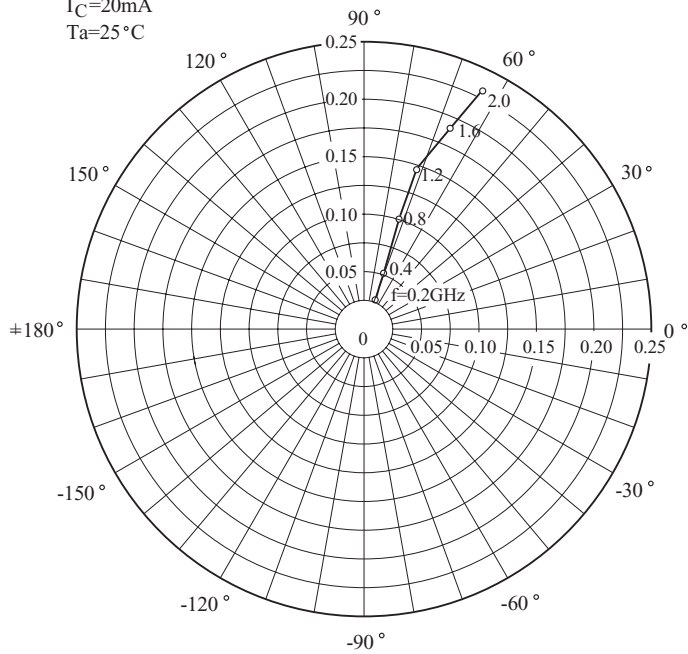
S_{11e}
V_{CE}=8V
I_C=20mA
T_a=25°C
(UNIT : Ω)



S_{21e}
V_{CE}=8V
I_C=20mA
T_a=25°C



S_{12e}
V_{CE}=8V
I_C=20mA
T_a=25°C



S_{22e}
V_{CE}=8V
I_C=20mA
T_a=25°C
(UNIT : Ω)

